



#### SINGLE N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
	57mΩ @ V <sub>GS</sub> = 10V	6.0A
30V	112mΩ @ V <sub>GS</sub> = 4.5V	3.8A

## **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

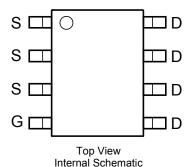
## **Features and Benefits**

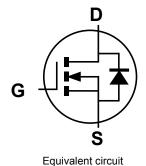
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOP-8L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Weight: 0.074g (approximate)







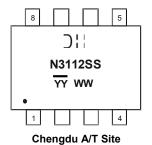
Ordering Information (Note 4)

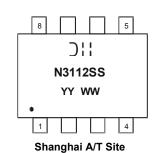
Part Number	Case	Packaging
DMN3112SSS-13	SOP-8L	2500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**





)|| = Manufacturer's Marking
N3112SS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 13 = 2013)
WW = Week (01 - 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			$V_{DSS}$	30	V
Gate-Source Voltage			$V_{GSS}$	±20	V
Drain Current (Note 5)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	6 4.5	А
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	24	A

### **Thermal Characteristics**

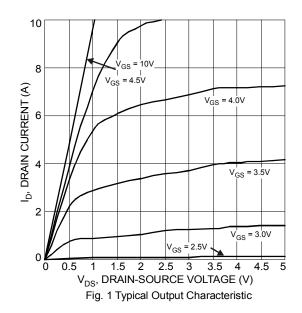
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P <sub>D</sub>	2.5	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	50	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C

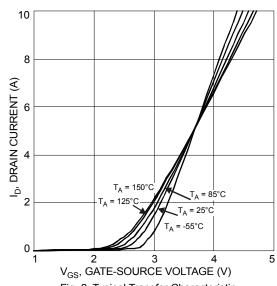
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	$BV_{DSS}$	30	_		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	800	nA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	_	_	_	±80	nΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
Gale-Source Leakage	I <sub>GSS</sub>	_	_	±800		$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(th)}$	1	_	2.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	43	57	l m()	$V_{GS} = 10V, I_D = 5.8A$	
Static Dialii-Source Off-Resistance			83	112		$V_{GS} = 4.5V, I_D = 3.7A$	
Forward Transconductance	<b>9</b> fs	_	2.8		S	$V_{DS} = 10V, I_D = 3.7A$	
Diode Forward Voltage (Note 7)	$V_{SD}$	0.5	0.8	1.2	V	$V_{GS} = 0V, I_S = 2.1A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C <sub>iss</sub>	_	268		pF	45)/ )/ 0)/	
Output Capacitance	C <sub>oss</sub>		73		pF	$V_{DS} = 15V, V_{GS} = 0V$ -f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	50	_	pF I = 1.0WH2		

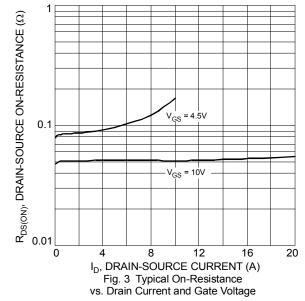
Notes:

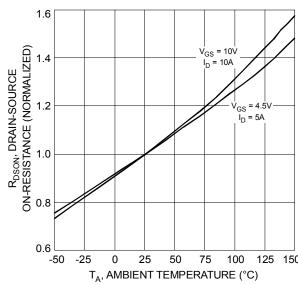
- 5. Device mounted on 2 oz copper pad layout with  $R_{\theta JA}$  = 50°C/W.
- 6. Pulse width ≤10µS, Duty Cycle ≤1%.
- 7. Short duration pulse test used to minimize self-heating effect.

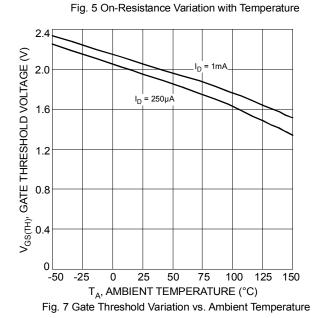












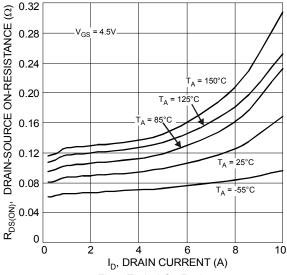


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

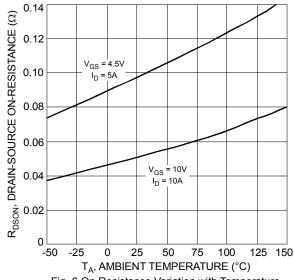
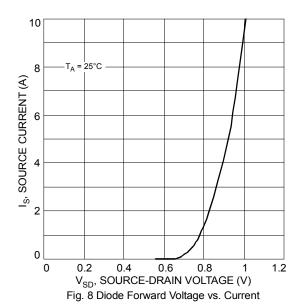
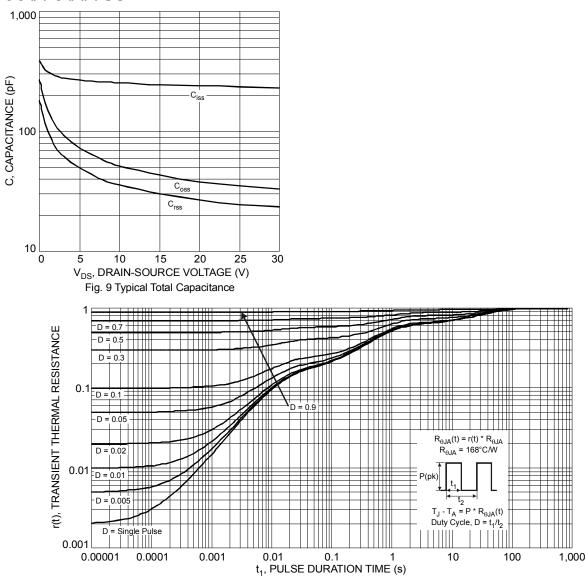


Fig. 6 On-Resistance Variation with Temperature

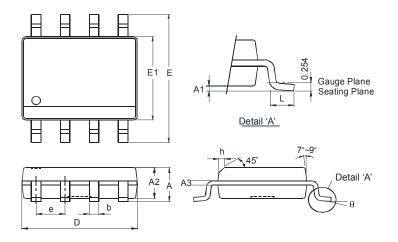






## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



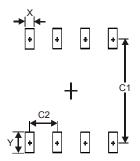
SOP-8L				
Dim	Min	Max		
Α	-	1.75		
A1	0.08	0.25		
A2	1.40	1.50		
A3	0.20 Typ			
b	0.3	0.5		
D	4.85	4.95		
Е	5.90	6.10		
E1	3.80	3.90		
е	1.27 Typ			
h	-	0.35		
Ĺ	0.60	0.80		
θ	0°	8°		
All Dimensions in mm				

Fig. 10 Transient Thermal Response



#### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Υ	1.55
C1	5.4
C2	1.27

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